

Abstracts

Progress of Microwave Semiconductor Devices in Japan

K. Sekido. "Progress of Microwave Semiconductor Devices in Japan." 1981 MTT-S International Microwave Symposium Digest 81.1 (1981 [MWSYM]): 177-178.

This paper reviews recent progress and development status of microwave semiconductor devices in Japan. Since in Japan, major development efforts have been concentrated to the GaAs MESFET devices developments, the paper provides particular emphasis to the introduction of GaAs MESFET device progress in Japan. Progress status in other semiconductor device area is also reviewed briefly.

 [Return to main document.](#)